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# FUSB340

## USB 3.1 SuperSpeed 10 Gbps Switch

### Features

- 10 GHz Typical Bandwidth
- USB 3.1 SuperSpeed 5 Gbps and 10 Gbps Switch
- -1.0 dB Typical Insertion Loss at 2.5 GHz
- Low Active Power of 12  $\mu$ A Typical
- Low Shutdown Power of < 1  $\mu$ A Max.
- 2 kV HBM ESD Protection
- Small Packaging, 18 Lead TMLP
- Wide  $V_{DD}$  Operating Range, 1.5 V-5.0 V

### Applications

- Smartphones
- Tablets
- Notebooks

### Description

The FUSB340 is a 2:1 data switch for USB SuperSpeed Gen1 and Gen2, 5 Gbps and 10 Gbps data. It is targeted at the mobile device market and for use in Type-C applications where a reversible cable requires a switch.

The FUSB340 data switch offers superior performance various high speed data transmission protocols:

- USB 3.1 SuperSpeed (Gen 2), 10 Gbps
- PCI Express, Gen 3
- SATA
- Fibre Channel
- Display Port 1.3

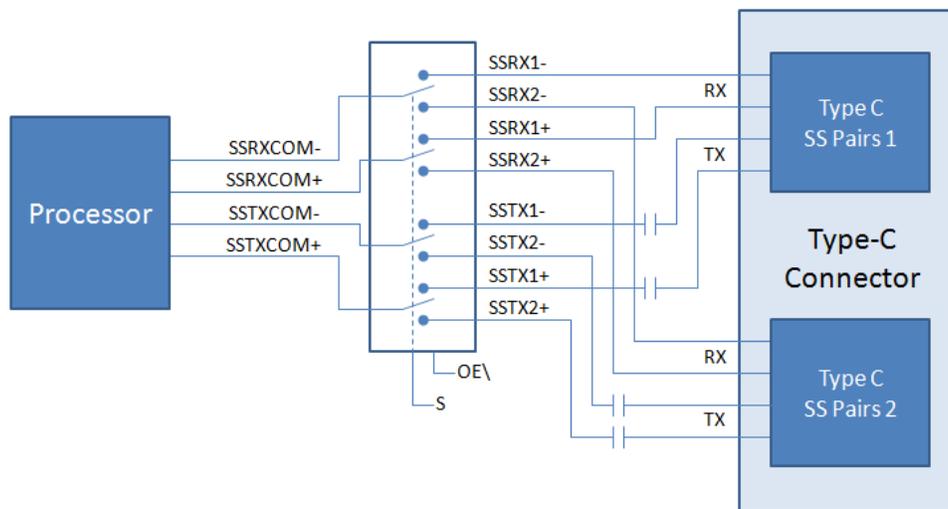


Figure 1. Block Diagram

### Ordering Information

Part Number	Operating Temperature Range	Package	Packing Method
FUSB340TMX	-40 to 85°C	18-Lead, Quad, Ultra-ultrathin Molded Leadless Package (TMLP), 2.0 mm x 2.8 mm x 0.375 mm	Tape and Reel

### Typical Application

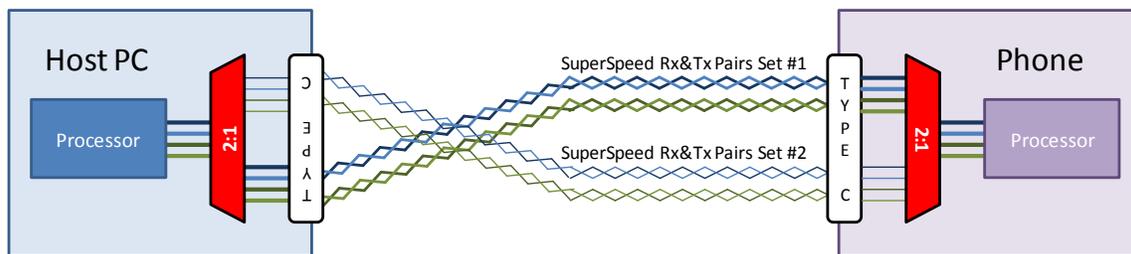


Figure 2. Typical Application

### Pin Configuration

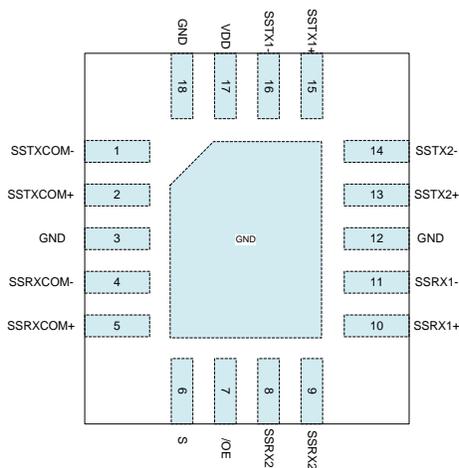


Figure 3. Pin Assignment (Top Through View)

### Pin Descriptions

Pin #	Name	Type	Description
1	SSTXCOM-	SW	SuperSpeed TX- Common
2	SSTXCOM+	SW	SuperSpeed TX+ Common
3	GND	GND	Ground (connected to die attach pad)
4	SSRXCOM-	SW	SuperSpeed RX- Common
5	SSRXCOM+	SW	SuperSpeed RX+ Common
6	S	Input	Switch Select (0=SW1, 1=SW2)
7	/OE	Input	Output Enable (0=Switches Enabled, 1=Switches Disabled)
8	SSRX2+	SW	SuperSpeed RX2+
9	SSRX2-	SW	SuperSpeed RX2-
10	SSRX1+	SW	SuperSpeed RX1+
11	SSRX1-	SW	SuperSpeed RX1-
12	GND	GND	Ground (connected to die attach pad)
13	SSTX2+	SW	SuperSpeed TX2+
14	SSTX2-	SW	SuperSpeed TX2-
15	SSTX1+	SW	SuperSpeed TX1+
16	SSTX1-	SW	SuperSpeed TX1-
17	V <sub>DD</sub>	VDD	Device Power
18	GND	GND	Ground

## Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Min.	Max.	Unit
V <sub>DD</sub>	Supply Voltage		-0.5	6.0	V
V <sub>CNTRL</sub>	DC Input Voltage (S, /OE) <sup>(1)</sup>		-0.5	V <sub>DD</sub>	V
V <sub>SW</sub>	DC Switch I/O Voltage <sup>(1,2)</sup>		-0.3	2.1	V
I <sub>IK</sub>	DC Input Diode Current		-50		mA
I <sub>SW</sub>	DC Switch Current			25	mA
T <sub>STG</sub>	Storage Temperature		-65	+150	°C
MSL	Moisture Sensitivity Level (JEDEC J-STD-020A)			1	
ESD	Human Body Model, JEDEC: JESD22-A114	All Pins	2		kV
	IEC 61000-2-4, Level 4, for Switch Pins	Contact	8		
		Air	15		
	Charged Device Model, JESD22-C101		1		

### Notes:

- The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.
- V<sub>SW</sub> refers to analog data switch paths.

## Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V <sub>DD</sub>	Supply Voltage	1.5	5.0	V
t <sub>RAMP(VDD)</sub>	Power Supply Slew Rate	100	1000	μs/V
V <sub>CNTRL</sub>	Control Input Voltage (S, /OE) <sup>(3)</sup>	0	5.0	V
V <sub>SW</sub>	Switch I/O Voltage (Both SSUSB Switch Paths)	0	2.0	V
T <sub>A</sub>	Operating Temperature	-40	+85	°C

### Note:

- The control inputs must be held HIGH or LOW; they must not float.

## DC and Transient Characteristics

All typical values are at  $T_A=25^\circ\text{C}$  unless otherwise specified.

Symbol	Parameter	Condition	$V_{DD}$ (V)	$T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$			Unit
				Min.	Typ.	Max.	
$V_{IK}$	Clamp Diode Voltage S, /OE	$I_{IN} = -18\text{ mA}$	1.5	-1.2		-0.6	V
$I_{IK}$	Clamp Diode Current (Switch Pins)	$V_{IN} = -0.3\text{ V}$	0			18	$\mu\text{A}$
$V_{IH}$	Control Input Voltage High	S, /OE	1.5	1.30			V
		S, /OE	3.6	1.4			V
		S, /OE	5.0	1.5			V
$V_{IL}$	Control Input Voltage Low	S, /OE	1.5			0.4	V
		S, /OE	3.6			0.4	V
		S, /OE	5.0			0.4	V
$I_{IN}$	Control Input Leakage	$V_{SW} = -0.6$ to $2.0\text{ V}$ $V_{CNTRL} = 0$ to $V_{DD}$	5.0	-500		500	nA
$I_{OZ}$	Off-State Leakage for Open Data Paths	$V_{SW} = 0.0 \leq \text{DATA} \leq 2.0\text{ V}$	5.0	-0.5		0.5	$\mu\text{A}$
$I_{CL}$	On-State Leakage for Closed Data Paths <sup>(4)</sup>	$V_{SW} = 0.0 \leq \text{DATA} \leq 2.0\text{ V}$	5.0	-0.5		0.5	$\mu\text{A}$
$I_{OFF}$	Power-Off Leakage Current (All I/O Ports)	$V_{SW} = 0\text{ V}$ or $2.0\text{ V}$	0	-500		500	nA
$R_{ON}$	Switch On Resistance	$V_{SW} = 0\text{ V}$ , $I_{ON} = -8\text{ mA}$	1.5		5.4	8.0	$\Omega$
$\Delta R_{ON}$	Difference in $R_{ON}$ Between Positive-Negative	$V_{SW} = 0\text{ V}$ , $I_{ON} = -8\text{ mA}$	1.5		0.1		$\Omega$
$R_{ONF}$	Flatness for $R_{ON}$	$V_{SW} = 0 \leq \text{DATA} \leq 2.0\text{ V}$ , $I_{ON} = -8\text{ mA}$	1.5		0.9		$\Omega$
$I_{CC}$	Quiescent Supply Current	$V_{/OE} = 0$ , $V_{SEL} = 0$ or $V_{DD}$ , $I_{OUT} = 0$	5.0		12	30	$\mu\text{A}$
$I_{CCZ}$	Quiescent Supply Current (High Impedance)	$V_{SEL} = X$ , $V_{/OE} = V_{DD}$ , $I_{OUT} = 0$	5.0			1	$\mu\text{A}$
$I_{CCT}$	Increase in Quiescent Supply Current per $V_{CNTRL}$	$V_{SEL}$ or $V_{/OE} = 1.5\text{ V}$	5.0		5	15	$\mu\text{A}$

**Note:**

4. For this test, the data switch is closed with the respective switch pin floating.

## AC Electrical Characteristics

All typical value are for  $V_{DD} = 3.6\text{ V}$  and  $T_A = 25^\circ\text{C}$  unless otherwise specified.

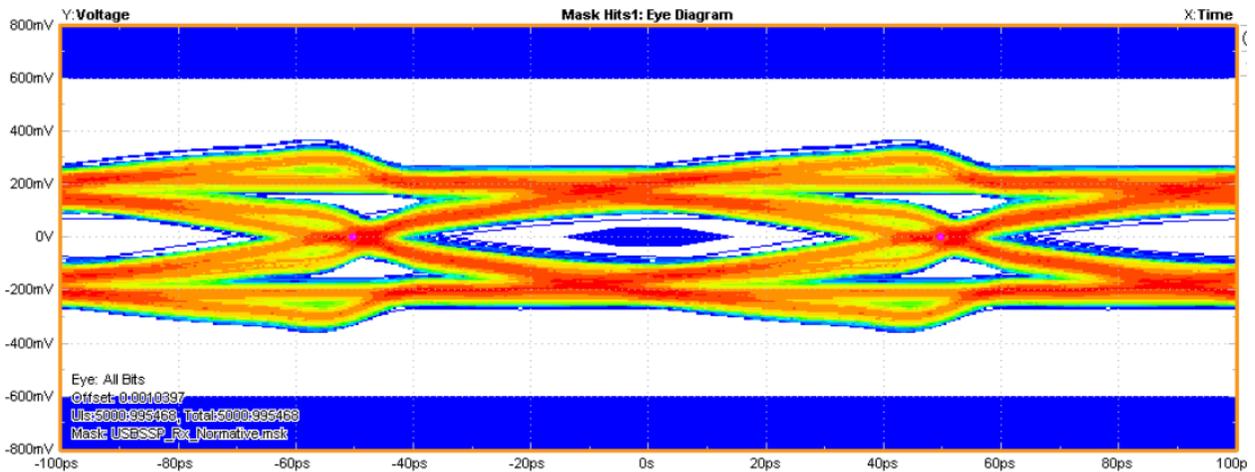
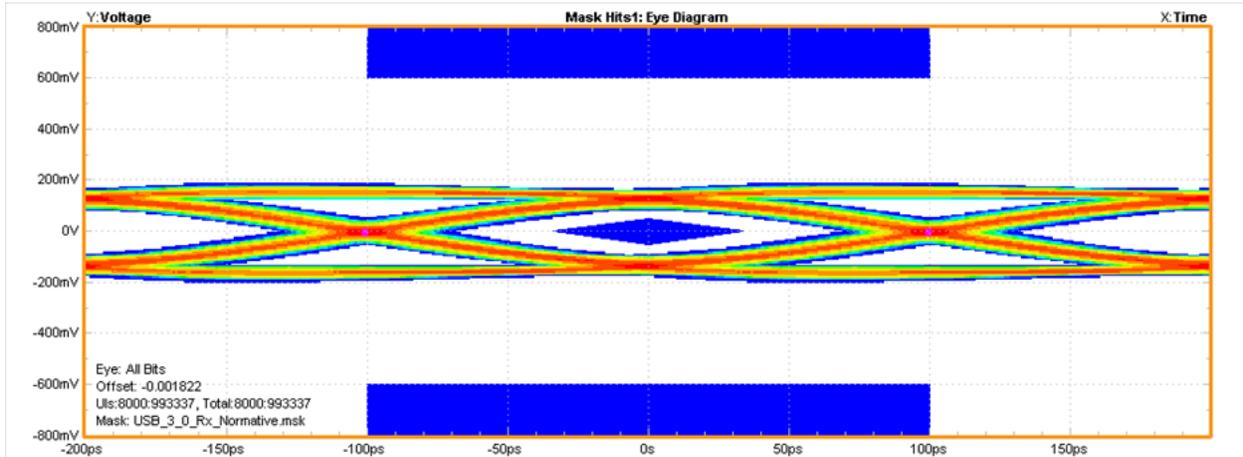
Symbol	Parameter	Condition	$V_{DD}$ (V)	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$			Unit
				Min.	Typ.	Max.	
$t_{ON}$	Turn-On Time, S to Output	$R_L = 50\ \Omega$ , $C_L = 0\ \text{pF}$ , $V_{SW} = 0\ \text{V}$ , $V_{SW} = 0.6\ \text{V}$	1.5 to 5.0 V		350	600	ns
$t_{OFF}$	Turn-Off Time, S to Output	$R_L = 50\ \Omega$ , $C_L = 0\ \text{pF}$ , $V_{SW} = 0\ \text{V}$ , $V_{SW} = 3.3\ \text{V}$	1.5 to 5.0 V		125	300	ns
$t_{ZHM,ZL}$	Enable Time, /OE to Output	$R_L = 50\ \Omega$ , $C_L = 0\ \text{pF}$ , $V_{SW} = 0.6\ \text{V}$	1.5 to 5.0 V		60	150	$\mu\text{s}$
$t_{LZM,HZ}$	Disable Time, /OE to Output	$R_L = 50\ \Omega$ , $C_L = 0\ \text{pF}$ , $V_{SW} = 0.6\ \text{V}$	1.5 to 5.0 V		35	240	ns
$t_{PD}$	Propagation Delay <sup>(5)</sup>	$C_L =$ , $C_L = 0\ \text{pF}$ , $R_L = 50\ \Omega$ ,	1.5 to 5.0 V		0.25		ns
$t_{BBM}$	Break-Before-Make <sup>(5)</sup>	$R_L = 50\ \Omega$ , $C_L = 0\ \text{pF}$ , $V_{SW1} = 0.6\ \text{V}$ , $V_{SW2} = -0.6\ \text{V}$ ,	1.5 to 5.0 V	100		350	ns
$DO_{IRR}$	Differential Off Isolation <sup>(5)</sup>	$V_S = 0\ \text{dBm}$ , $R_L = 50\ \Omega$ , $f = 2.5\ \text{GHz}$	3.6 V		-28		dB
		$V_S = 0\ \text{dBm}$ , $R_L = 50\ \Omega$ , $f = 5.0\ \text{GHz}$			-25		
SDDNEXT	Differential Channel Crosstalk <sup>(5)</sup>	$V_S = 0\ \text{dBm}$ , $R = 50\ \Omega$ , $f = 2.5\ \text{GHz}$	3.6 V		-44		dB
		$V_S = 0\ \text{dBm}$ , $R = 50\ \Omega$ , $f = 5.0\ \text{GHz}$			-40		
DIL	Differential Insertion Loss <sup>(5)</sup> (All Data Paths)	$V_{IN} = 0\ \text{dBm}$ , $f = 2.5\ \text{GHz}$ , $R_L = 50\ \Omega$ , $C_L = 0\ \text{pF}$	3.6 V		-1.0		dB
		$V_{IN} = 0\ \text{dBm}$ , $f = 5.0\ \text{GHz}$ , $R_L = 50\ \Omega$ , $C_L = 0\ \text{pF}$			-1.8		
BW	Differential -3 dB Bandwidth <sup>(5)</sup>	$V_{IN} = 1\ \text{V}_{pk-pk}$ , $R_L = 50\ \Omega$ , $C_L = 0\ \text{pF}$ , (Both Data Paths)	3.6 V		10		GHz
$t_{SK(P)}$	Skew of Opposite Transitions of the Same Output <sup>(5)</sup>	$R_{PU} = 50\ \Omega$ to $V_{DD}$ , $C_L = 0\ \text{pF}$	3.6 V		6		ps
$C_{IN}$	Control Pin Input Capacitance <sup>(5)</sup>	$V_{DD} = 0\ \text{V}$ , $f = 1\ \text{MHz}$			2.7		pF
$C_{ON}$	On Capacitance <sup>(5)</sup>	$V_{DD} = 3.3\ \text{V}$ , $f = 2.5\ \text{GHz}$			0.5		pF
$C_{OFF}$	Off Capacitance <sup>(5)</sup>	$V_{DD} = 3.3\ \text{V}$ , $f = 2.5\ \text{GHz}$			0.4		pF

**Note:**

- Guaranteed by characterization.

## Eye Diagrams

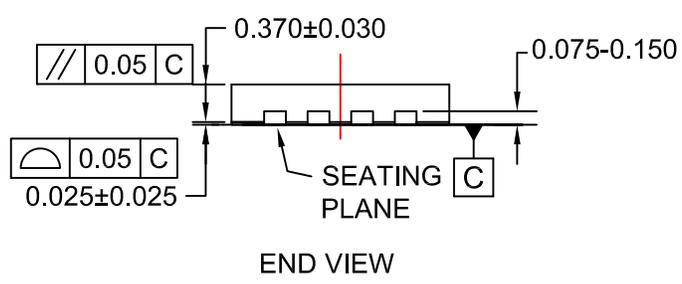
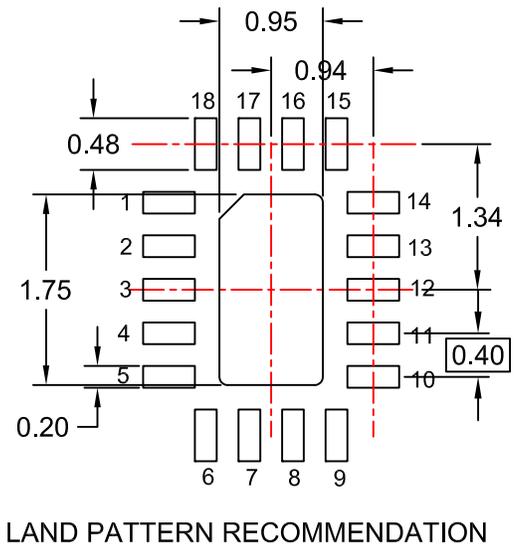
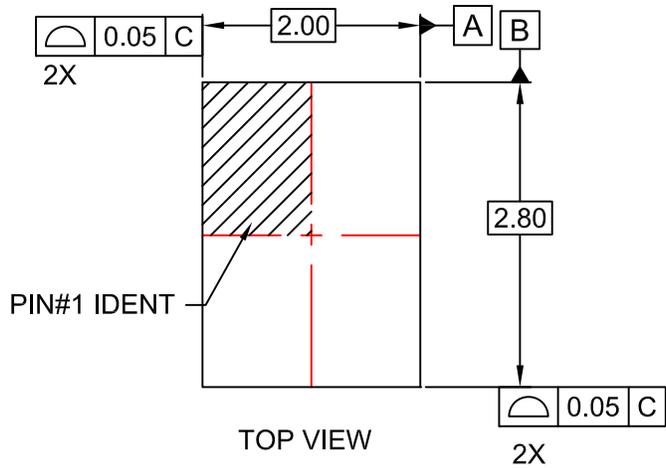
All plots below are for  $V_{DD}=3.6\text{ V}$  and  $T_A=25^\circ\text{C}$  with 0 dBm differential data.



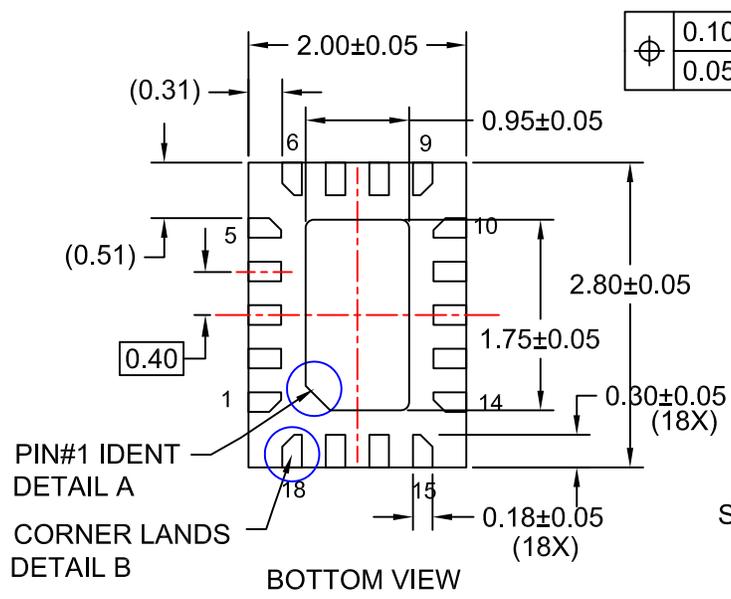
The table below pertains to the UMLP Package drawing on the following page.

### Product-Specific Dimensions

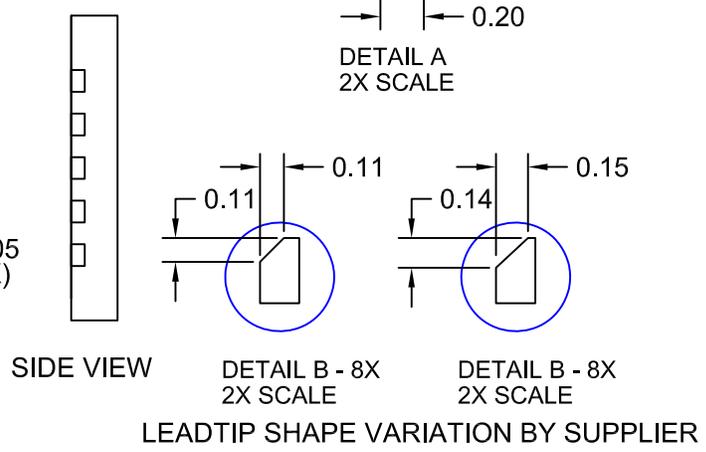
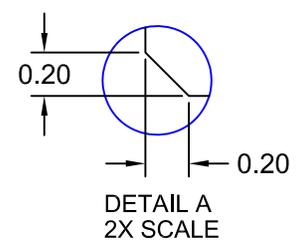
Product	A	B
FUSB340TMX	2.00 mm	2.80 mm



- NOTES:
- A. NO INDUSTRY STANDARD APPLIES.
  - B. DIMENSIONS ARE IN MILLIMETERS.
  - C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
  - D. LAND PATTERN RECOMMENDATION IS A FAIRCHILD DESIGN.
  - E. DRAWING FILENAME: MKT-TMLP18Arev2



⊕	0.10	C	A	B
	0.05	C		



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